xxxFN (JEDEC SOP) is not available in

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCT139AF,TC74VHCT139AFN,TC74VHCT139AFT,TC74VHCT139AFK

Note:

Japan.

Dual 2-to-4 Line Decoder

The TC74VHCT139A is an advanced high speed CMOS 2 to 4 LINE DECODER/DEMULTIPLEXER fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The active low enable input can be used for gating or it can be used as a data input for demultiplexing applications.

When the enable input is held High, all four outputs are fixed at a high logic level independent of the other inputs.

The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing $3.3\ V$ to $5\ V$ system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output $^{\rm (Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: $V_{CC} = 0 V$

Features

- High speed: $t_{pd} = 5.0 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25^{\circ}C$
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V (max)}$ $V_{IH} = 2.0 \text{ V (min)}$
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 139 type.

SOP16-P-300-1.27A
TC74VHCT139AFN

SOL16-P-150-1.27
TC74VHCT139AFT

TSSOP16-P-0044-0.65A
TC74VHCT139AFK

Weight

 SOP16-P-300-1.27A
 : 0.18 g (typ.)

 SOL16-P-150-1.27
 : 0.13 g (typ.)

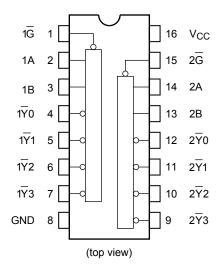
 TSSOP16-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP16-P-0030-0.50
 : 0.02 g (typ.)

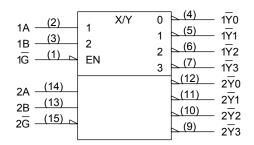
VSSOP16-P-0030-0.50

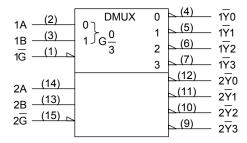


Pin Assignment



IEC Logic Symbol



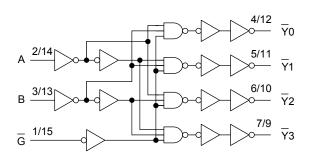


Truth Table

Inp		Out	0 1 1						
Enable	Select		<u></u>	<u>-</u> Y1		- 73	Selected Output		
G	В	Α	10	11	12	13	7		
Н	Х	Х	Н	Н	Н	Н	None		
L	L	L	L	Н	Н	Н	₹0		
L	L	Н	Н	L	Н	Н	Y 1		
L	Н	L	Н	Н	L	Н	₹2		
L	Н	Н	Н	Н	Н	L	- - - - -		

X: Don't care

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	−0.5 to 7.0	V	
DC input voltage	V _{IN}	−0.5 to 7.0	V	
DC output voltage	V	-0.5 to 7.0 (Note 2)	V	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	lok	±20 (Note 4)	mA	
DC output current	lout	±25	mA	
DC V _{CC} /ground current	Icc	±50	mA	
Power dissipation	PD	180	mW	
Storage temperature	T _{stg}	−65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	٧
Output voltage	Vour	0 to 5.5 (Note 2)	٧
Output voltage	Vout	0 to V _{CC} (Note 3)	V
Operating temperature	T _{opr}	−40 to 85	°C
Input rise and fall time	dt/dV	0 to 20	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
Onaracteristics	Cymbol				Min	Тур.	Max	Min	Max	Onit
High-level input voltage	V _{IH}	_			2.0	_	_	2.0	_	V
Low-level input voltage	V _{IL}	-			_	_	0.8	_	0.8	V
High-level output	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.40	4.50	_	4.40	_	٧
voltage			I _{OH} = -8 mA	4.5	3.94	_	_	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.1	_	0.1	V
			I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±1.0	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	_	40.0	μΑ
	Ісст	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	_	1.50	mA
Output leakage current	I _{OPD}	V _{OUT} = 5.5 V			_	_	0.5	_	5.0	μΑ

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
Propagation delay	t _{pLH} t _{pHL}		5.0 ± 0.5	15	-	5.0	7.2	1.0	8.5	ns
time (A, B- \overline{Y})		_		50	_	6.5	9.2	1.0	10.5	
Propagation delay time	t _{pLH}			15	_	5.0	7.2	1.0	8.5	
(G-Y)	t _{pHL}	_	5.0 ± 0.5	50	_	6.5	9.2	1.0	10.5	ns
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	ı	32	ı	ı	ı	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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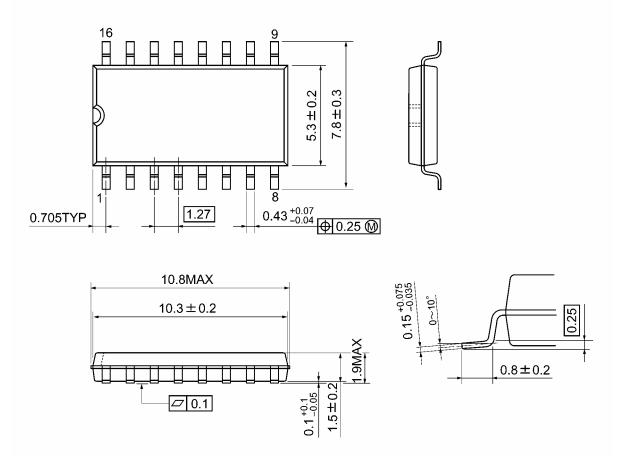
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 (per decoder)$



Package Dimensions

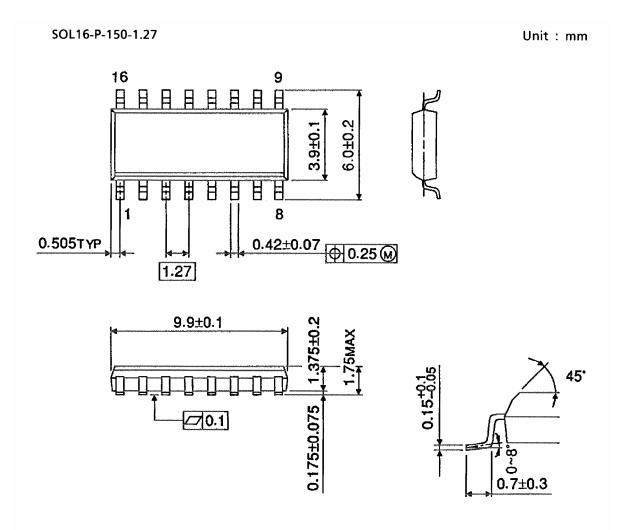
SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)



Package Dimensions (Note)



6

Note: This package is not available in Japan.

Weight: 0.13 g (typ.)



Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm

0.225TYP

0.65

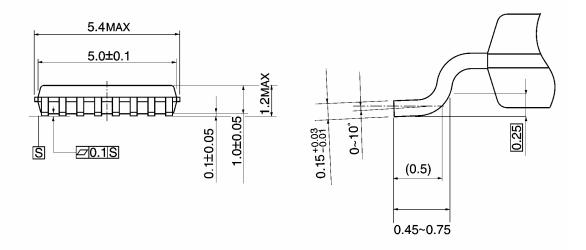
0.22^{+0.09}

0.053

0.22^{+0.09}

0.13

0.20

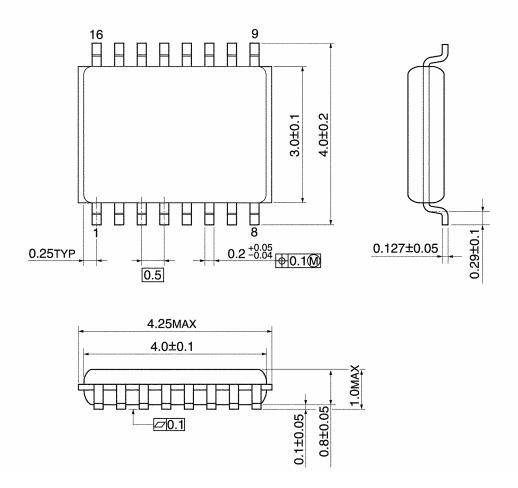


Weight: 0.06 g (typ.)



Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



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Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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